Power Schottky Rectifier

I_{FAV} = 10 A
V_{RRM} = 100 V
V_F = 0.66 V

| V_{RSM} | V_{RRM} | Type | |
V	V		
100	100	DSS 10-01A	DSS 10-01AS

A ◯—▷|—◯ C
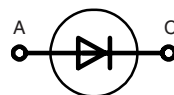
TO-263 AB
(...S-Type)

TO-220 AC

C (TAB)
C
A
C
A
C (TAB)
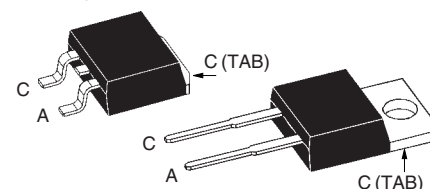
A = Anode, C = Cathode , TAB = Cathode

Symbol	Conditions	Maximum Ratings	
I_{FRMS}		35	A
I_{FAV}	T_C = 160°C; rectangular, d = 0.5	10	A
I_{FSM}	T_{VJ} = 45°C; t_p = 10 ms (50 Hz), sine	120	A
E_{AS}	I_{AS} = 5 A; L = 100 µH; T_{VJ} = 25°C; non repetitive	1.3	mJ
I_{AR}	V_A =1.5 • V_{RRM} typ.; f=10 kHz; repetitive	0.8	A
$(dv/dt)_{cr}$		5000	V/µs
T_{VJ}		-55...+175	°C
T_{VJM}		175	°C
T_{stg}		-55...+150	°C
P_{tot}	T_C = 25°C	90	W
M_d	mounting torque (A-Type only)	0.4...0.6	Nm
Weight	typical	2	g

Features

- International standard package
- Very low V_F
- Extremely low switching losses
- Low I_{RM}-values
- Epoxy meets UL 94V-0

Applications

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Advantages

- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- Low losses

Dimensions see Outlines.pdf

| Symbol | Conditions | Characteristic Values | |
		typ.	max.
I_R ①	V_R = V_{RRM}; T_{VJ} = 25°C		0.3 mA
	V_R = V_{RRM}; T_{VJ} = 125°C		2.5 mA
V_F	I_F = 10 A; T_{VJ} = 125°C		0.66 V
	I_F = 10 A; T_{VJ} = 25°C		0.84 V
	I_F = 20 A; T_{VJ} = 125°C		0.80 V
R_{thJC}			1.7 K/W
R_{thCH}		0.5	K/W

Pulse test: ① Pulse Width = 5 ms, Duty Cycle < 2.0 %
Data according to IEC 60747 and per diode unless otherwise specified.

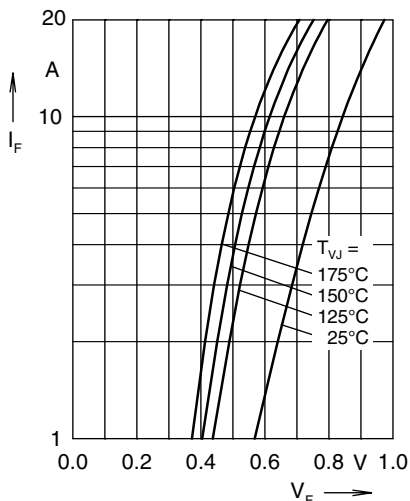IXYS reserves the right to change limits, Conditions and dimensions.

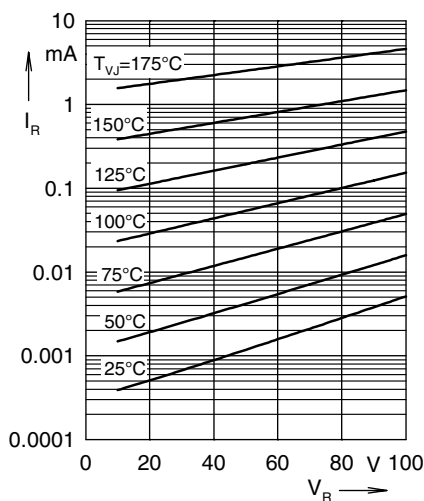Fig. 1 Maximum forward voltage drop characteristics

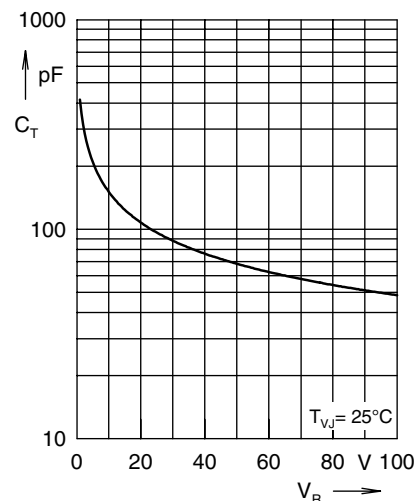Fig. 2 Typ. reverse current I_R vs: reverse voltage V_R

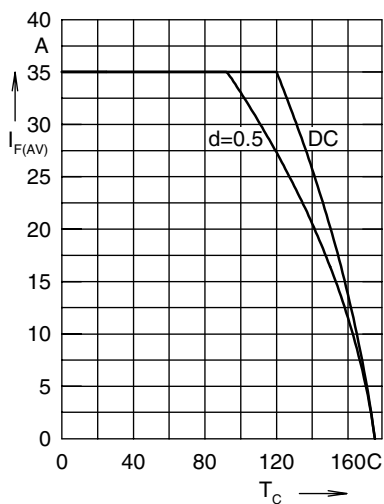Fig. 3 Typ. junction capacitance C_T versus reverse voltage V_R

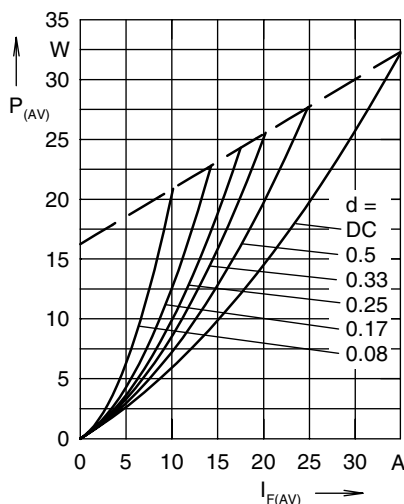Fig. 4 Avg: forward current $I_{F(AV)}$ vs: case temperature T_C
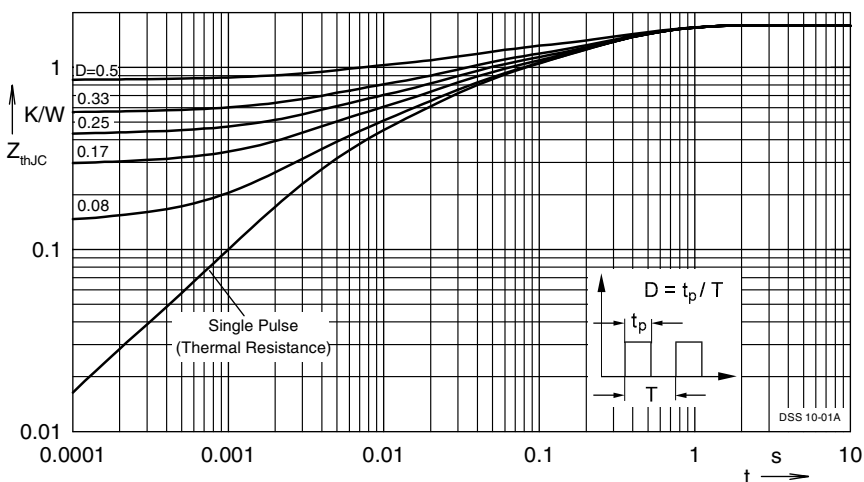
Fig. 5 Forward power loss characteristics

Note: All curves are per diode

Fig. 6 Transient thermal impedance junction to case at various duty cycles